NSN 5961-01-109-0652

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Inclosure Material:

Metal

Overall Length:

1.573 inches

Overall Height:

0.450 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

160.0 collector to base voltage/static/emitter open and 140.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage,

static, collector open

Current Rating Per Characteristic:

90.00 amperes source cutoff current and 15.00 amperes source cutoff current

Power Rating Per Characteristic:

175.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

18876-13060906 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin and 1 case Shelf Life: N/a Unit Of Measure: --Demilitarization: No

Fiig:

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